L6450

SGS-THOMSON MICROELECTRONICS

28 CHANNEL INK JET DRIVER

ADVANCE DATA

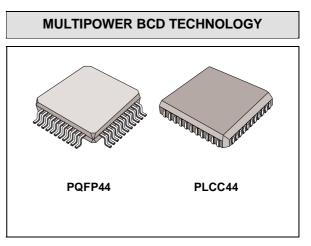
- 40V DMOS OUTPUT BREAKDOWN
- TWO DECODER OPTIONS ARE INCLUDED
- PRECISE OUTPUT ENERGY
- ESD OUTPUT PROTECTION WITH CLAMP-ING DIODES
- VERY LOW QUIESCENT CURRENT
- PLCC44 OR PQFP44 (10 x 10mm)

DESCRIPTION

The L6450 is realized in Multipower BCD Technology which combines isolated DMOS power transistors with CMOS and Bipolar circuits on the same IC. By using mixed technology it has been possible to optimize the logic circuitry and the power stage to achieve the best possible performances.

Intended to be used in ink jet Printer Applications as 4 to 28 (2 x 14) or 3 to 28 (4 x 7) lines selectable decoder/driver, the L6450 device driver has the advantages of low power CMOS inputs and logic, with 28 high current and high voltage DMOS outputs capable of sustaining a maximum of 40V.

On system power up the output drivers are locked out using the chip enable function; four enable in-



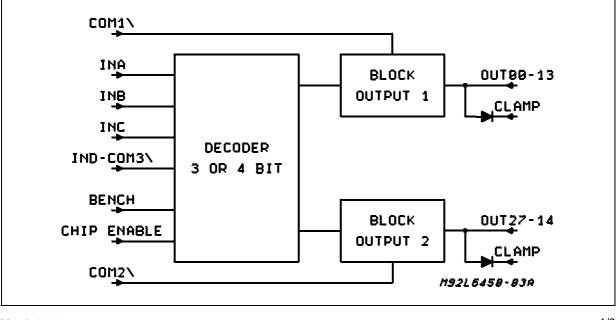
puts are available for the different driver banks.

An internal power-on system is implemented in order to avoid wrong output commutation during the supply voltage transients.

Using a mask option during manufacturing allows a different decoding.

Control of the energy delivered to the print head is made by means of a special circuitry.

All driver outputs are capable of withdstanding a contact discharge of $\pm 8 \text{KV}$ with the IC biased.

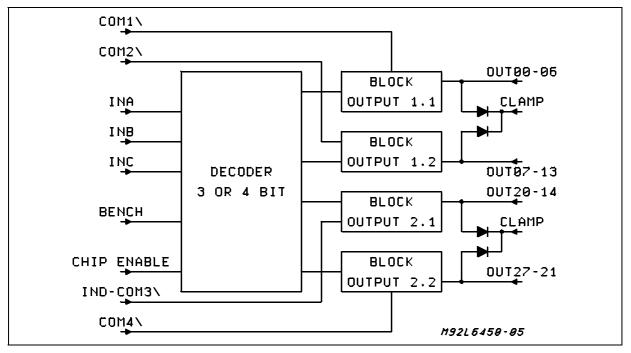


BLOCK DIAGRAM (case of 4 bit)

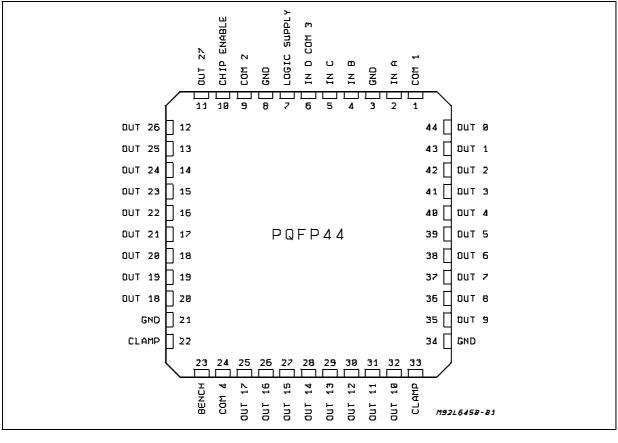
March 1994

This is advanced information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

BLOCK DIAGRAM (case of 3 bit)



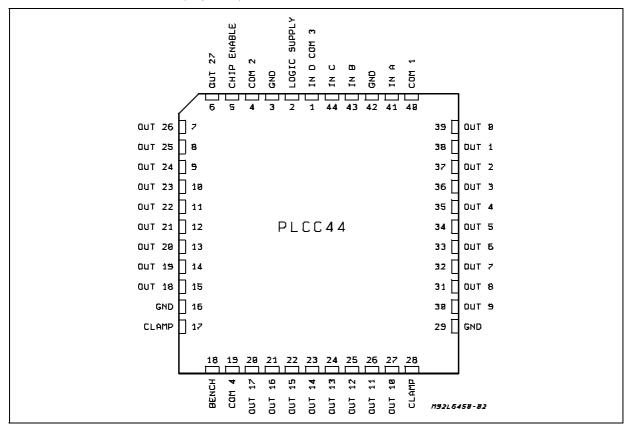
PQFP44 PIN CONNECTION (Top view)



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PLCC44 PIN CONNECTION (Top view)



PIN FUNCTIONS

Name	Function
V _{DD}	5V Logic Supply.
GND	Logic and Power Ground.
OUT0 to OUT27	DMOS Outputs.
CLAMP	This pins have to be connected to the power supply voltage of the head resistors, each of the output DMOS have their drain connected with the anode of a protection diode, all the catodes of the protection diodes are collected to the pins clamp. If the CLAMP pins are not connected to the power, the device is not supplied.
INA, INB, INC, IND	Decoder inputs. The input IND shares the pin with the other input $\overline{\text{COM3}}$, the two different functions are selected by the pin Bench.
<u>COM1,</u> <u>COM2,</u> COM3, COM4	A low logic input on this pins enable the outputs selected by the decoder inputs according to the logic level of the pin bench. The input COM3 shares the pin with the other input IND, the two different functions are selected by the pin Bench.
CHIP ENABLE	A logic high enable the chip.

THERMAL DATA

Symbol	Parameter	PQFP44	PLCC44	Unit
R _{th} j-amb	Thermal Resistance Junction-Ambient Max.	55 (*)	65 (*)	°C/W

(*) device mounted on PCB.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vout	Output Voltage	40	V
VCLAMP	Output Clamping Voltage	40	V
I _{OUT}	Output Continuous Current	0.8	А
IPEAK	Output Peak Current (with duty cycle = $10\% T_{ON} = 4\mu s$)	2	А
TJ	Junction Temperature	150	°C
V _{DD}	Logic Supply Voltage	7	V
VIN	Input Voltage Range	-0.3V to V _S +0.3	V
T _{amb}	Operating Temperature Range	0 to 70	°C
T _{stg}	Storage Temperature Range	-55 to 150	°C

D.C. ELECTRICAL CHARACTERISTICS at $T_{amb} = 25^{\circ}C$, $V_{DD} = 5V$, $V_{clamp} = 18V$ (unless otherwise specified).

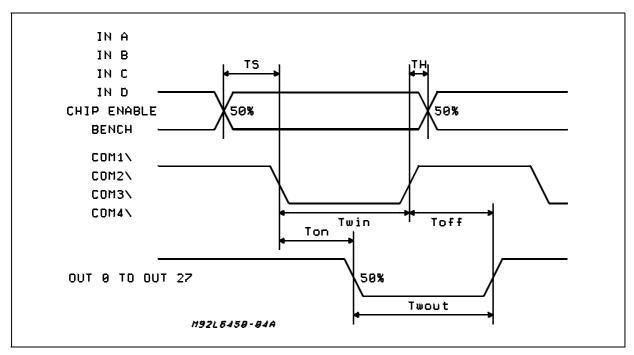
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{DD}	Logic Supply Voltage		4.75	5	5.25	V
V _{CLAMP}	Clamping Voltage		9		38	V
VIL	Low Level Input Voltage				1.2	V
VIH	High Level Input Current		V _{DD} -1.2			V
ILL	Low Level Input Current	$V_{IN} = V_{IL}$			-200	μA
I _{LH}	High Level Input Current	$V_{IN} = V_{IH}$			10	μA
I _{DD}	Logic Supply Current	(Indipendent from the output conditions)			5	mA
Vout	Output Saturation Voltage	Tj 25 °C D.C. 0.4A Tj 25 °C D.C. 0.5A Tj 90 °C D.C. 0.4A Tj 90 °C D.C. 0.5A		0.9 1.1 1.4 1.7		>>>>
ΔV_{CE}	Output saturation absolute voltage variation around the typ. values for extended temperature ranges	Tj = 25°C to 90°C D.C.: 0.4A Tj = 25°C to 90°C D.C.: 0.5A			±0.2 ±0.25	V V
R _{DS} ON				2.2		Ω

A.C. ELECTRICAL CHARACTERISTICS at $T_{amb} = 25^{\circ}C$, $V_{DD} = 5V$.

Symbol	Signal Name	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Τs	INA, INB, INC, IND Vs COMn	SET - UP Time		30			ns
Т _Н	INA, INB, INC, IND Vs COMn	HOLD Time		0			ns
Ton	COM1,2,3,4 V _S OUT 0 to N	TURN - ON Time	$I_{OUT} = 0.5A, R_L = 39\Omega$ T _j = 25 to 90°C		150		ns
T _{off}	COM1,2,3,4 V _S OUT 0 to N	TURN - OFF Time	$\begin{array}{l} I_{OUT}=0.5\text{A}, \text{R}_{\text{L}}=39\Omega\\ \text{T}_{\text{j}}=25 \text{ to }90^{\circ}\text{C} \end{array}$		150		ns
tr		Rise Time			100		ns
t _f		Fall Time			100		ns
T _{wout}		Output Pulse Width	$T_{win} = 3.5 \mu s R_L = 40 \Omega$ I _{OUT} = 0.5A	- 20	T_{win}	+ 80	ns
ΔΡ _D		Maximum allowable variation of the output power transmitted by each driver to the resistive load	$R_L = 39\Omega$ $V_{CLAMP} = 18V$			±4	%







OUTPUT SELECTION

- 1)Decoder Truth Table when the BENCH = HIG<u>H;</u>
 - $IND/\overline{COM3}$ = is selected as input decoder ind; COM1 = a low input enable the OUT0 to OUT13;COM2 = A Low Input Enable the OUT14 to
 - OUT27

IND	INC	INB	INA (LSB)	OUTPUTS
0	0	0	0	0.27
0	0	0	1	1.26
0	0	1	0	2.25
0	0	1	1	3.24
0	1	0	0	4.23
0	1	0	1	5.22
0	1	1	0	6.21
0	1	1	1	7.20
1	0	0	0	8.19
1	0	0	1	9.18
1	0	1	0	10.17
1	0	1	1	11.16
1	1	0	0	12.15
1	1	0	1	13.14
1	1	1	0	ALL OFF
1	1	1	1	ALL OFF

2)Decoder Truth Table when the BENCH = LOW: IND/COM3 = is selected as COM3

COM1: A Low Input Enable the OUT0 to OUT6 COM2: A Low Input Enable the OUT7 to

OUT13 COM3: A Low Input Enable the OUT14 to

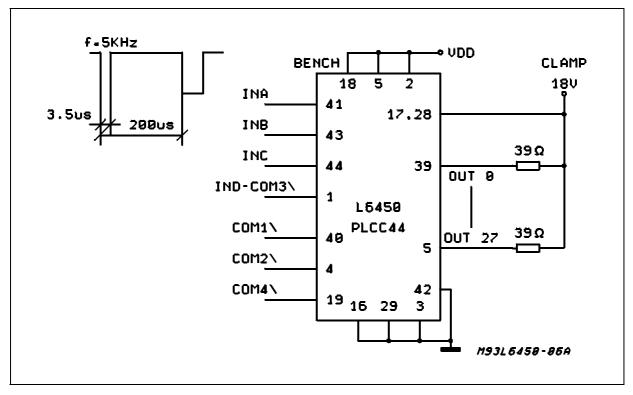
OUT20 COM4: A Low Input Enable the OUT21 to OUT27

INC	INB	INA (LSB)	OUTPUTS
0	0	0	0, 7,27, 20
0	0	1	1, 8, 26, 19
0	1	0	2, 9, 25, 18
0	1	1	3, 10, 24, 17
1	0	0	4, 11, 23, 16
1	0	1	5, 12, 22, 15
1	1	0	6, 13, 21, 14
1	1	1	ALL OFF



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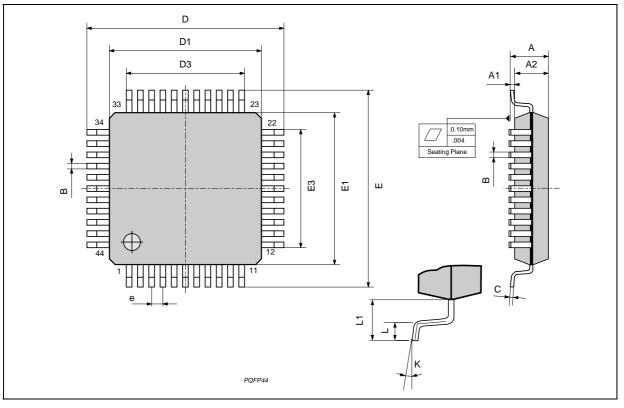
Figure 2: Application Circuit





DIM.		mm			inch	
Dim.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			3.40			0.134
A1	0.25			0.0098		
A2	2.55	2.80	3.05	0.100	0.110	0.120
В	0.35		0.50	0.0138		0.0197
С	0.13		0.23	0.005		0.009
D	16.95	17.20	17.45	0.667	0.677	0.687
D1	13.90	14.00	14.10	0.547	0.551	0.555
D3		10.00			0.394	
е		1.00			0.039	
E	16.95	17.20	17.45	0.667	0.677	0.687
E1	13.90	14.00	14.10	0.547	0.551	0.555
E3		10.00			0.394	
L	0.65	0.80	0.95	0.025	0.0315	0.0374
L1		1.60			0.063	
К	0°(min.), 7°(max.)					

PQFP44 (14 x 14) PACKAGE MECHANICAL DATA

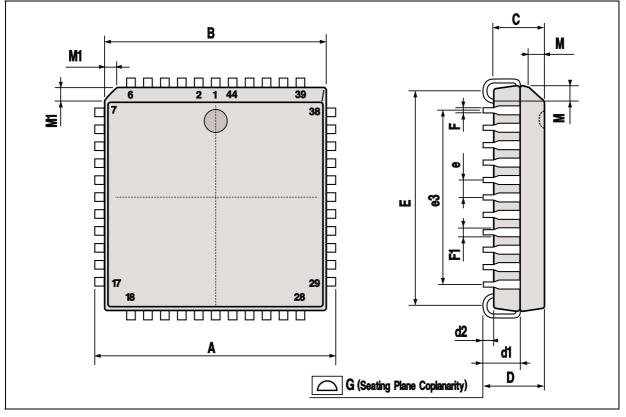




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mm inch DIM. MIN. TYP. MAX. MIN. TYP. MAX. А 17.4 17.65 0.685 0.695 В 16.51 16.65 0.650 0.656 С 3.7 0.144 3.65 0.146 D 4.2 4.57 0.165 0.180 2.59 2.74 0.102 d1 0.108 d2 0.68 0.027 Е 14.99 16 0.590 0.630 1.27 0.050 е e3 12.7 0.500 F 0.46 0.018 F1 0.71 0.028 G 0.101 0.004 Μ 1.16 0.046 M1 1.14 0.045





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